<u>TOSHIBA</u>

TOSHIBA Power Transistor Module Silicon NPN Epitaxial Type (Four Darlington Power Transistors in One)

MP4501

High Power Switching Applications

Hammer Drive, Pulse Motor Drive and Inductive Load Switching

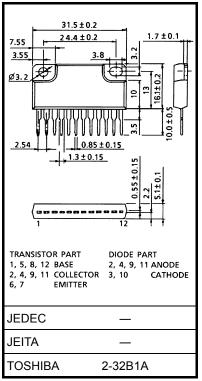
- Package with heat sink isolated to lead (SIP 12 pins)
- High collector power dissipation (4-device operation) : $P_T = 5 \text{ W} (T_a = 25^{\circ}\text{C})$
- High collector current: IC (DC) = 3 A (max)
- High DC current gain: $h_{FE} = 2000 \text{ (min)} (V_{CE} = 2 \text{ V}, I_C = 1.5 \text{ A})$
- Diode included for absorbing fly-back voltage

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V _{CBO}	120	V
Collector-emitter voltage		V _{CEO}	100	V
Emitter-base voltage		V _{EBO}	6	V
Collector ourrept	DC	Ι _C	3	Α
Collector current	Pulse	I _{CP}	6	A
Continuous base current		Ι _Β	0.5	A
Collector power dissipation (1-device operation)		P _C	3.0	W
Collector power dissipation	Ta = 25°C	•Рт	5.0	w
(4-device operation)	Tc = 25°C		25	vv
Isolation voltage		V _{Isol}	1000	V
Junction temperature		Tj	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C

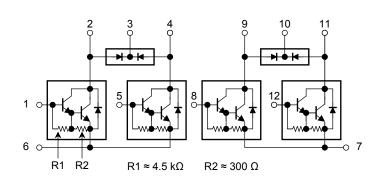






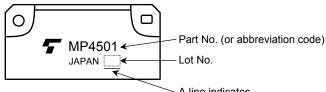
Weight: 6.0 g (typ.)

Array Configuration



TOSHIBA

Marking



A line indicates
 lead (Pb)-free package or
 lead (Pb)-free finish.

Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient	ΣR _{th (j-a)}	25	°C/W	
(4-device operation, Ta = 25°C)				
Thermal resistance from junction to case	ΣR _{th (j-c)}	5.0	°C/W	
(4-device operation, Tc = 25°C)	,			
Maximum lead temperature for soldering purposes	TL	260	°C	
(3.2 mm from case for 10 s)				

Electrical Characteristics (Ta = 25°C)

Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off cu	rrent	I _{CBO}	V _{CB} = 120 V, I _E = 0 A	_	_	10	μA
Collector cut-off cu	rrent	ICEO	V _{CE} = 100 V, I _B = 0 A	_	—	10	μA
Emitter cut-off curre	ent	I _{EBO}	V _{EB} = 6 V, I _C = 0 A	0.5	_	2.5	mA
Collector-base brea	akdown voltage	V (BR) CBO	I _C = 1 mA, I _E = 0 A	120	—	_	V
Collector-emitter bi	reakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0 A	100	_	_	V
DC ourrent goin		h _{FE (1)}	V _{CE} = 2 V, I _C = 1.5 A	2000	—	15000	
DC current gain	h _{FE (2)}	V _{CE} = 2 V, I _C = 3 A	1000	_	_	—	
Saturation voltage	Collector-emitter	V _{CE (sat)}	I _C = 1.5 A, I _B = 3 mA	_	—	1.5	V
	Base-emitter	V _{BE (sat)}	I _C = 1.5 A, I _B = 3 mA	_	_	2.0	
Transition frequence	cy	fT	V _{CE} = 2 V, I _C = 0.5 A	_	60	_	MHz
Collector output ca	pacitance	C _{ob}	V _{CB} = 10 V, I _E = 0 A, f = 1 MHz	_	30	_	pF
Turn-on time Switching time Storage time Fall time	ton	Input → Output	_	0.3	_		
	Storage time	t _{stg}	$ \begin{array}{c} 20 \ \mu s \\ \hline 10 \ \mu s \\$	_	2.0	_	μs
	Fall time	tŗ	$I_{B1} = -I_{B2} = 3 \text{ mA, duty cycle ≤ 1%}$	_	0.4	_	

TOSHIBA

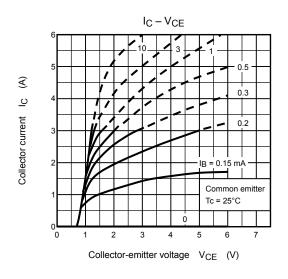
Emitter-Collector Diode Ratings and Characteristics (Ta = 25°C)

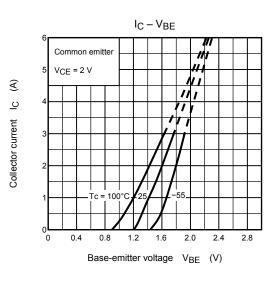
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Maximum forward current	I _{FM}	—	_	_	3	А
Surge current	I _{FSM}	t = 1 s, 1 shot	_	_	6	А
Forward voltage	VF	I _F = 1 A, I _B = 0 A	_	1.2	1.8	V
Reverse recovery time	t _{rr}	I _F = 3 A, V _{BE} = −3 V, dI _F /dt = −50 A/µs	_	1.0	—	μs
Reverse recovery charge	Q _{rr}		_	5	_	μC

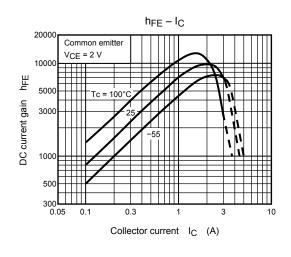
Flyback-Diode Rating and Characteristics (Ta = 25°C)

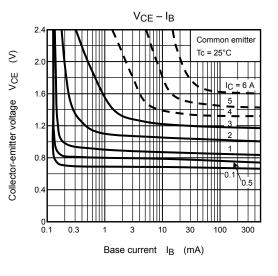
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Maximum forward current	I _{FM}	—	—	—	3	А
Reverse current	I _R	V _R = 120 V	_	_	0.4	μA
Reverse voltage	V _R	I _R = 100 μA	120	_	_	V
Forward voltage	V _F	I _F = 0.5 A			1.8	V

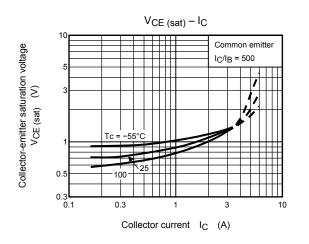
TOSHIBA

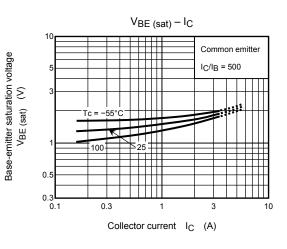


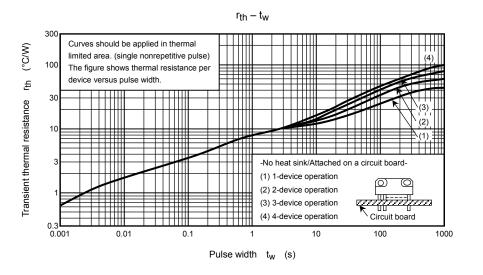


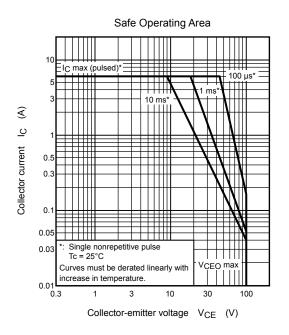


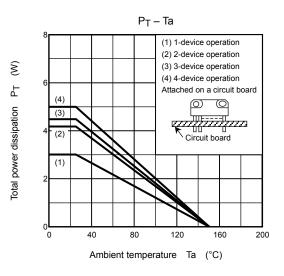


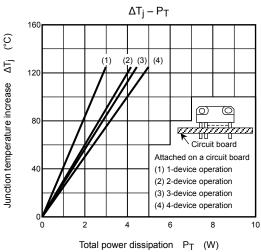












RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.).These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.